

# Preparation and Electrochemical Properties of SnO<sub>2</sub> Nanowires for Application in Lithium-Ion Batteries\*\*

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One-dimensional (1D) nanostructured materials have received considerable attention for advanced functional systems as well as extensive applications owing to their attractive electronic, optical, and thermal properties.<sup>[1-2]</sup> In lithium-ion-battery science, recent research has focused on nanoscale electrode materials to improve electrochemical performance. The high surface-to-volume ratio and excellent surface activities of 1D nanostructured materials have stimulated great interest in their development for the next generation of power sources.<sup>[3-4]</sup>

Materials based on tin oxide have been proposed as alternative anode materials with high-energy densities and stable capacity retention in lithium-ion batteries.<sup>[5-7]</sup> Various SnO<sub>2</sub>-based materials have displayed extraordinary electrochemical behavior such that the initial irreversible capacity induced by Li<sub>2</sub>O formation and the abrupt capacity fading caused by volume variation could be effectively reduced when in nanoscale form.<sup>[8-10]</sup> From this point of view, SnO<sub>2</sub> nanowires can also be suggested as a promising anode material because the nanowire structure is of special interest with predictions of unique electronic and structural properties. Furthermore, the nanowires can be easily synthesized by a thermal evaporation method. However, in its current form, this method of manufacture of SnO<sub>2</sub> nanowires has several limitations: it is inappropriate for mass production as high synthesis temperatures are required and there are difficulties

in the elimination of metal catalysts that could act as impurities or defects. This results in reversible capacity loss or poor cyclic performance during electrochemical reactions.<sup>[11,12]</sup> The critical issues relating to SnO<sub>2</sub> nanowires as anode materials for lithium-ion batteries are how to avoid the deteriorative effects of catalysts and how to increase production.

Herein, we report on the preparation and electrochemical performance of self-catalysis-grown SnO<sub>2</sub> nanowires to determine their potential use as an anode material for lithium-ion batteries. SnO<sub>2</sub> nanowires have been synthesized by thermal evaporation combined with a self-catalyzed growth procedure by using a ball-milled evaporation material to increase production at lower temperature and prevent the undesirable effects of conventional catalysts on electrochemical performance. The self-catalysis-grown SnO<sub>2</sub> nanowires show higher initial coulombic efficiency and an improved cyclic retention compared with those of SnO<sub>2</sub> powder and SnO<sub>2</sub> nanowires produced by Au-assisted growth.<sup>[11]</sup>

The self-catalysis growth method, which uses a ball-milled mixture of SnO and Sn powder as an evaporation source, is appropriate for obtaining SnO<sub>2</sub> nanowires with high purity. The deposited products on the Si substrates contain almost 100% of the SnO<sub>2</sub> nanowires formed. Observation with scanning electron microscopy (SEM) clearly shows a general view of randomly aligned SnO<sub>2</sub> nanowires with diameters of 200–500 nm and lengths extending to several tens of micrometers (Figure 1 a). Sn droplets at the tips of nanowires were observed and confirmed by energy dispersive X-ray (EDX)

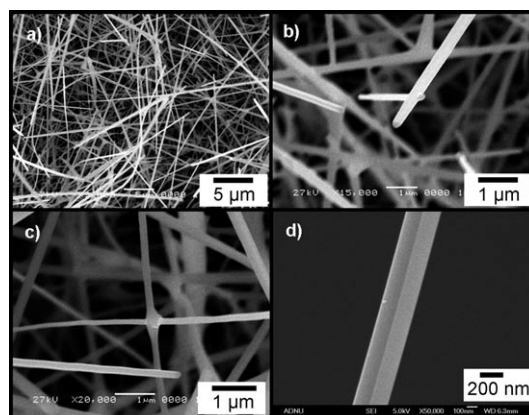
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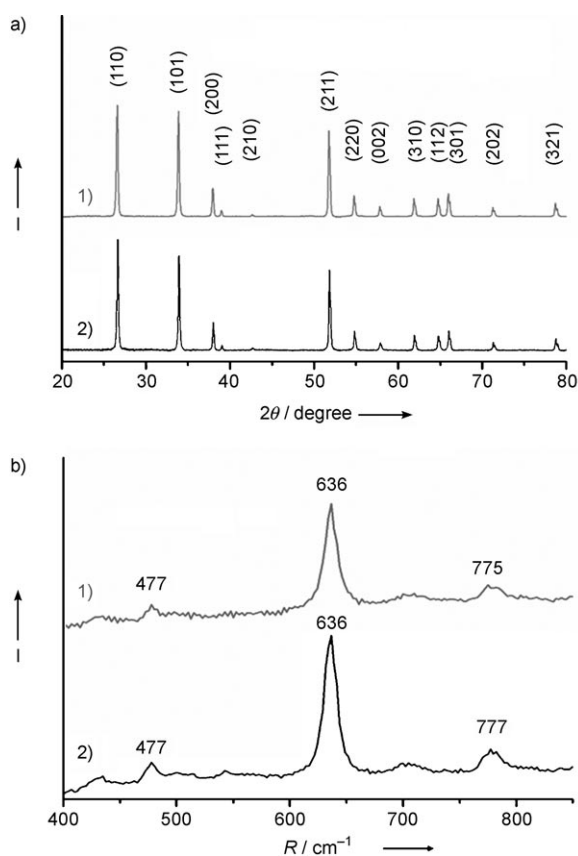
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**Figure 1.** The microstructure of self-catalysis-grown SnO<sub>2</sub> nanowires. a) SEM image of SnO<sub>2</sub> nanowires; b) SEM image of tips including Sn droplets; c) SEM image of junction; and d) field-emission SEM (FESEM) image of an individual nanowire stem.

spectroscopy (Figure 1 b and c). In regards to the low melting point of Sn (231.9°C), it is suggested that Sn particles in the starting material form liquid nuclei on the Si substrate at the initial stage of the evaporation above 300°C, leading to vapor–liquid–solid (VLS) growth of the SnO<sub>2</sub> nanowires at 900°C. The Sn droplets were essential for growth of SnO<sub>2</sub> nanowires without conventional catalysts and for determining the diameters of nanowires. More interestingly, close inspection of the stem of an individual nanowire showed a quadrilateral cross-section (Figure 1 d), which is in agreement with a tetragonal structure.

Figure 2 a shows an X-ray diffraction (XRD) pattern of SnO<sub>2</sub> nanowires compared with that of SnO<sub>2</sub> powder. All reflections of SnO<sub>2</sub> nanowires are in excellent accordance with a tetragonal rutile structure (JCPDS 41-1445), which

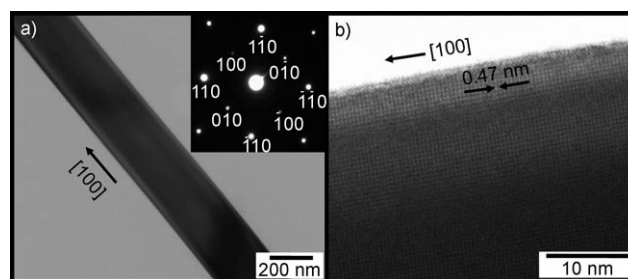


**Figure 2.** a) X-ray diffraction patterns of SnO<sub>2</sub> nanowires (1) and SnO<sub>2</sub> powder (2). b) Room-temperature Raman spectra of SnO<sub>2</sub> nanowires (1) and SnO<sub>2</sub> powder (2). I = intensity, R = Raman shift.

belongs to the space group  $P4_2/mnm$  (number 136). The lattice parameters of the nanowires were  $a = b = 4.738 \text{ \AA}$  and  $c = 3.188 \text{ \AA}$ . It is well known that a nanowire form with a high aspect ratio experiences more tensile stress along the  $c$  axis direction on the surface than the powder form, which leads to an increase in the  $c$  value. In accord with this,  $c$ -axis-related peak shifts to lower angles were detected for SnO<sub>2</sub> nanowires when compared with the powder; the shifts of the nanowires

were  $\Delta(2\theta) = 0.063^\circ$ ,  $0.067^\circ$ , and  $0.058^\circ$  for the (101), (002), and (301) peaks, respectively. The full width at half maximum (FWHM) of the (002) peak for SnO<sub>2</sub> nanowires and SnO<sub>2</sub> powder were calculated to be  $0.2800^\circ$  and  $0.3400^\circ$ , respectively. The apparently smaller FWHM for the (002) peak indicates that the nanowires have better crystallinity with fewer lattice distortions along the  $c$  axis in the tetragonal system. From the XRD results, the  $c$ -axis-related peak shifts and FWHM behavior provided evidence of an increase in the  $c$  axis parameter in the nanowire lattice structure. Figure 2 b shows Raman spectra of the SnO<sub>2</sub> nanowires compared with SnO<sub>2</sub> powder. The fundamental Raman scattering peaks for SnO<sub>2</sub> powder were observed at  $477 \text{ cm}^{-1}$ ,  $636 \text{ cm}^{-1}$ , and  $777 \text{ cm}^{-1}$ , corresponding to the E<sub>g</sub>, A<sub>1g</sub>, and B<sub>2g</sub> vibration modes, respectively.<sup>[9]</sup> We also found these peaks in the Raman spectra of SnO<sub>2</sub> nanowires at  $477 \text{ cm}^{-1}$ ,  $636 \text{ cm}^{-1}$ , and  $775 \text{ cm}^{-1}$ . The downwards shift of the B<sub>2g</sub> vibration mode for SnO<sub>2</sub> nanowires could be caused by the size effect of the structure.<sup>[12]</sup> These results are also consistent with formation of self-catalysis-grown SnO<sub>2</sub> nanowires with a single crystalline structure.

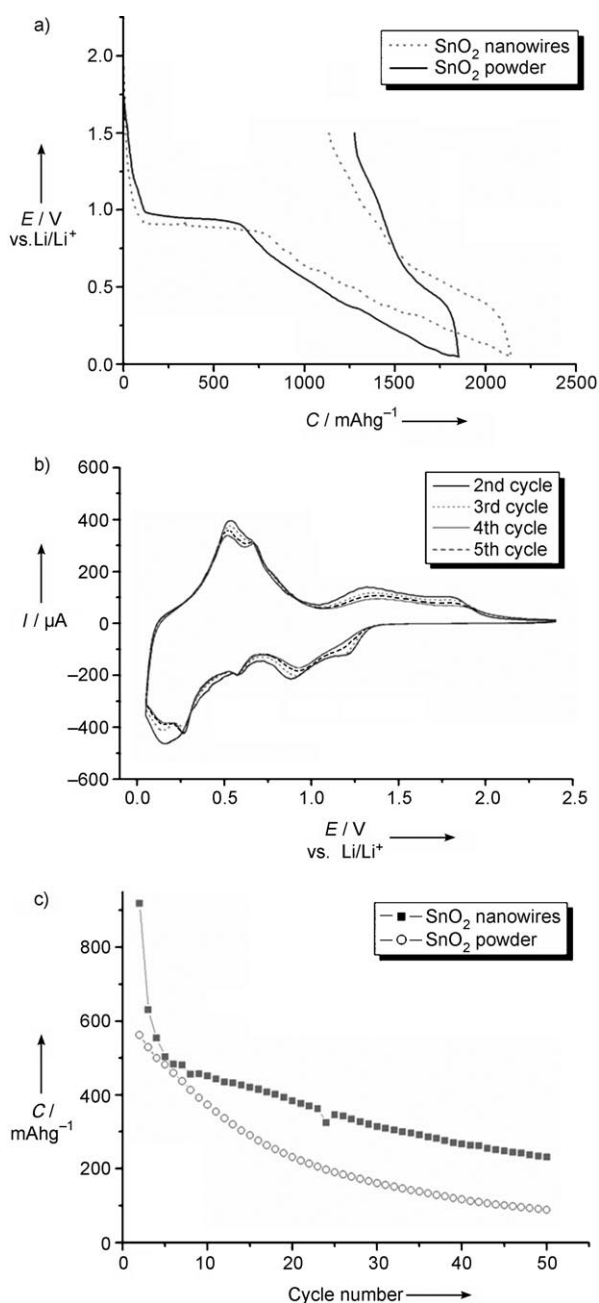
TEM bright-field imaging combined with selected-area diffraction (SAD) revealed the fine microstructure of the SnO<sub>2</sub> nanowires, each wire being a monocrystal with a tetragonal structure (Figure 3 a). Tilting experiments also



**Figure 3.** a) TEM image and SAD patterns (inset) of a SnO<sub>2</sub> nanowire. Zone axis is [001]. b) HRTEM image of a section of a SnO<sub>2</sub> nanowire.

revealed no evidence of extended defects within the individual crystals. High-resolution (HR) imaging was combined with SAD to investigate the nanowire growth direction. For the wire shown in Figure 3 a, the zone axis is [001] and the growth direction of the nanowire is parallel to [100]. The HRTEM image (Figure 3 b) confirms this, with an interplanar spacing of approximately 0.47 nm between neighboring [100] planes of tetragonal SnO<sub>2</sub>.

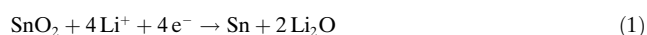
The anodic performance of SnO<sub>2</sub> nanowires was tested in the potential range of 0.05 to 1.5 V (versus Li/Li<sup>+</sup>). For comparative purposes, SnO<sub>2</sub> powder was also examined under the same conditions. The SnO<sub>2</sub> nanowires show much higher Li<sup>+</sup> storage and a relatively smaller initial irreversible capacity of 1134 mAh g<sup>-1</sup> in the galvanostatic voltage profiles for the first cycle, as shown in Figure 4 a. Note that the SnO<sub>2</sub> nanowires show an initial coulombic efficiency of approximately 46.91%, which is notably higher than that of the SnO<sub>2</sub> powders (31.01%). The improvement of electrochemical



**Figure 4.** The anodic performance of the SnO<sub>2</sub> nanowires. a) The galvanostatic voltage profile ( $C$  = capacity,  $E$  = potential) for the first cycle between 0.05 V and 1.5 V compared with pure SnO<sub>2</sub> powder. b) Cyclic voltammograms from the second cycle to the fifth cycle at a scan rate of 0.05 mVs<sup>-1</sup> in the voltage range of 0.05–2.5 V. c) The cyclic performance from the second cycle to the 50th cycle of SnO<sub>2</sub> nanowires and pure SnO<sub>2</sub> powder at the same current density, 100 mA g<sup>-1</sup>.  $C$  = discharge capacity.

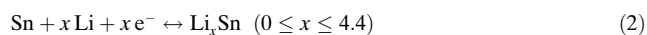
behavior should be attributed to the 1D nanowire structure with a large surface area and high length/diameter ratio. The 1D nanowire structure could provide more reaction sites on the surface, and the smaller diameter of the nanowires provides a short diffusion length for Li<sup>+</sup> insertion, which could enhance the charge transfer and electron conduction along

the length direction. More importantly, the Sn droplets on the tips of nanowires could also contribute to the Li<sup>+</sup> storage and reduce the pulverization owing to lattice mismatches at the interfaces between nanowires and catalysts, which would result in improvements in the initial coulombic efficiency and Li<sup>+</sup> storage. To identify electrochemical reactions during cycles, cyclic voltammograms (CV) of SnO<sub>2</sub> nanowires were obtained and are presented in Figure 4b. The CV profiles show two apparent reduction peaks around 0.95 V and 1.20 V derived from Li<sub>2</sub>O formation and electrolyte decomposition when SnO<sub>2</sub> nanowires react with Li<sup>+</sup> as described in Equation (1).<sup>[8]</sup> These peaks should disappear, leaving a



large initial irreversible capacity after the first cycle in SnO<sub>2</sub> powder electrodes. However, these irreversible reactions were still taking place until the fifth cycle in SnO<sub>2</sub> nanowire electrodes. We suggest that the single-crystalline structure of nanowires may disturb smooth Li<sup>+</sup> insertion into the interior of the nanowires, which leads to a slow lithiation. Furthermore, the additional electrolyte decomposition on the new surface induced by volume expansion may result in irreversible capacity even after the first cycle. Based on these considerations, the Li<sub>2</sub>O formation and electrolyte decomposition might continue through subsequent cycles, leading to an increasing irreversible capacity up to the fifth cycle, as shown in Figure 4c.

The other pairs of reduction and oxidation peaks at 0.25 V and 0.6 V during the discharge and at 0.5 V and 0.7 V during the charge cycles are related to the formation of Li<sub>*x*</sub>Sn as described in Equation (2).<sup>[8]</sup> The self-catalysis-grown SnO<sub>2</sub>



nanowires exhibit improved cyclic performance and a higher reversible specific capacity of over 300 mAh g<sup>-1</sup> up to the 50th cycle as shown in Figure 4c. This suggests that the 1D nanowire structure with a high aspect ratio of length to diameter effectively increases the charge-transfer properties along the length direction compared with the powder form. Moreover, the self-catalysis-grown SnO<sub>2</sub> nanowires show a smaller capacity fading of 1.45% per cycle after the fifth cycle, which is much smaller than that of SnO<sub>2</sub> nanowires grown through Au assistance (3.89%).<sup>[11]</sup> It is likely that the reversible capacity loss or electrical disconnection induced by the traditional metal catalysts could be effectively reduced in the self-catalysis-grown SnO<sub>2</sub> nanowires.

In summary, we have fabricated self-catalysis-grown SnO<sub>2</sub> nanowires by a thermal evaporation process. The ball-milled evaporation source served to increase production and decrease the synthesis temperature. The Sn particles in the evaporation source played the role of the catalyst, allowing VLS growth of the SnO<sub>2</sub> nanowires. The 1D nanowire structure could provide more reaction sites on the surface and enhance the charge transfer in the electrochemical reactions. Moreover, Sn particles at the tips of nanowires also contributed to the Li<sup>+</sup> storage and prevented the capacity loss that is induced by the existing metal catalysts.

## Experimental Section

The thermal evaporation process was employed to synthesize SnO<sub>2</sub> nanowires. As an evaporation source, high purity SnO (99.99%, Aldrich) and Sn (99.99%, Aldrich) powders were homogeneously mixed in a 1:1 weight ratio by a planetary mechanical milling process for 40 h under an atmosphere of argon. Ball-milled powder (1 g) was placed in an alumina boat located inside a tube furnace. Silicon substrates without metal catalysts were placed downstream one by one at a distance of about 15 cm from the powder. The heating temperature and time were optimized at 900 °C and 1 h, respectively. The deposition pressure was 100 Torr of high purity Ar gas at a flow rate of 50 sccm (standard cubic centimeters per minute). The morphology and microstructure of self-catalysis-grown SnO<sub>2</sub> nanowires were characterized by XRD (Philips 1730), SEM (JEOL JEM-3000), TEM (JEOL 2011), and Raman spectroscopy (Jobin Yvon HR800). The SnO<sub>2</sub> nanowires were mixed with acetylene black (AB) and a binder (poly(vinylidene fluoride); PVdF) at a weight ratio of 75:15:10, respectively, in a solvent (*N*-methyl-2-pyrrolidone). The slurry was uniformly pasted on Cu foil. Such prepared electrode sheets were dried at 120 °C in a vacuum oven and pressed under a pressure of approximately 200 kg cm<sup>-2</sup>. CR2032-type coin cells were assembled for electrochemical characterization. The electrolyte was 1 M LiPF<sub>6</sub> in a 1:1 mixture of ethylene carbonate and dimethyl carbonate. Li metal foil was used as the counter and reference electrode. The cells were galvanostatically charged and discharged at a current density of 100 mA g<sup>-1</sup> over a range of 0.05 V to 1.5 V.

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